MOS FET Relays

G3VM-61B1/E1

Analog-switching MOS FET Relay for **High Switching Currents, with Dielectric** Strength of 2.5 kVAC between I/O.

- Upgraded G3VM-61 B/E Series.
- Switches minute analog signals.
- Leakage current of 1 μA max. when output relay is open.

■ Application Examples

- Measurement devices
- · Security systems
- · Amusement machines



NEW Approval pending

Note: The actual product is marked differently from the image shown here.

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	60 VAC	G3VM-61B1	50	
	Surface-mounting		G3VM-61E1		
	terminals		G3VM-61E1(TR)		1,500

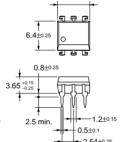
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

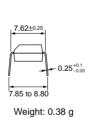




Note: The actual product is marked different-ly from the image



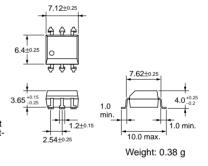
2.54+0.25



G3VM-61E1

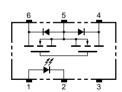


The actual product is marked different-ly from the image

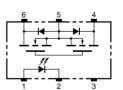


■ Terminal Arrangement/Internal Connections (Top View)

G3VM-61B1

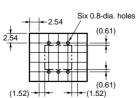


G3VM-61E1



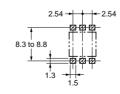
■ PCB Dimensions (Bottom View)

G3VM-61B1



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61E1



■ Absolute Maximum Ratings (Ta = 25°C)

	.								
	Item		Symbol	Rating	Unit	Measurement Conditions			
Input	LED forward current		I _F	50	mA				
	Repetitive peak LED forward current		I _{FP}	1	Α	100 μs pulses, 100 pps			
	LED forward current reduction rate		Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C			
	LED reverse voltage		V_R	5	V				
	Connection temperature		Tj	125	°C				
Output	Output dielectric strength		V _{OFF}	60	V				
	Continuous load current	Connection A	I _O	500	mA				
		Connection B		500					
		Connection C		1,000					
	ON current reduction rate	Connection A	Δ I _{ON} / $^{\circ}$ C	-0.5	mA/°C	Ta ≥ 25°C			
		Connection B		-0.5					
		Connection C		-10.0					
	Connection temperature		Tj	125	°C				
Dielectric strength between input and output (See note 1.)		V _{I-O}	2,500	Vrms	AC for 1 min				
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation				
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation				
Soldering temperature (10 s)			260	°C	10 s				

Note:
1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

Connection Diagram

Connection

A

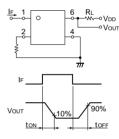
Connection

Connect

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions		
Input	put LED forward voltage		V_{F}	1.0	1.15	1.3	V	I _F = 10 mA	
Reverse current Capacity between terminals		I _R			10	μА	V _R = 5 V		
		ninals	C _T		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current		I _{FT}		1.6	3	mA	I _O = 500 mA	
Output	Maximum resistance with output ON	Connection A	R _{ON}		1	2	Ω	I _F = 5 mA, I _O = 500 mA	
		Connection B			0.5	1	Ω	I _F = 5 mA, I _O = 500 mA	
		Connection C			0.25		Ω	I _F = 5 mA, I _O = 1,000 mA	
	Current leakage when the relay is open		I _{LEAK}			1.0	μА	V _{OFF} = 60 V	
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V		
Insulation resistance			R _{I-O}	1,000			ΜΩ	$V_{I\text{-}O}$ = 500 VDC, RoH \leq 60%	
Turn-ON time			tON		0.8	2.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$	
Turn-OFF time			tOFF		0.1	0.5	ms	$V_{DD} = 20 \text{ V (See note 2.)}$	

Note: 2. Turn-ON and Turn-OFF Times



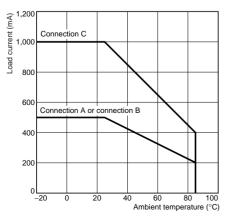
■Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}			48	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	I _O			500	mA
Operating temperature	Ta	- 20		65	°C

■Engineering Data

Load Current vs. Ambient Temperature G3VM-61B1(E1)



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.